NST489AMT1G, NSVT489AMT1G

High Current Surface Mount NPN Silicon Low V_{CE(sat)} Switching Transistor for Load Management in Portable Applications

Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS (T_A = 25° C)

Rating	Symbol	Max	Unit
Collector-Emitter Voltage	V _{CEO}	30	V
Collector-Base Voltage	V _{CBO}	50	V
Emitter-Base Voltage	V _{EBO}	5.0	V
Collector Current – Continuous	Ι _C	2.0	A
Collector Current – Peak	I _{CM}	3.0	А

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit		
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	P _D (Note 1)	535 4.3	mW mW/°C		
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$ (Note 1)	234	°C/W		
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	P _D (Note 2)	1.180 9.4	W mW/°C		
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$ (Note 2)	106	°C/W		
Thermal Resistance, Junction-to-Lead #1	${\sf R}_{ heta JL}$ (Note 1) ${\sf R}_{ heta JL}$ (Note 2)	110 50	°C/W °C/W		
Total Device Dissipation (Single Pulse < 10 s)	P _{Dsingle} (Notes 2 and 3)	1.75	W		
Junction and Storage Temperature Range	T _J , T _{stg}	–55 to +150	°C		

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. FR-4 with 1 oz and 3.9 mm^2 of copper area.

2. FR-4 with 1 oz and 645 mm² of copper area.

3. Refer to Figure 8.



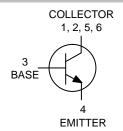
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30 VOLTS, 3.0 AMPS NPN TRANSISTOR



TSOP-6 CASE 318G STYLE 6



DEVICE MARKING



N2 = Specific Device Code

M = Date Code*

= Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
NST489AMT1G	TSOP–6 (Pb–Free)	3,000 / Tape & Reel
NSVT489AMT1G	TSOP–6 (Pb–Free)	3,000 / Tape & Reel

⁺For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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NST489AMT1G, NSVT489AMT1G

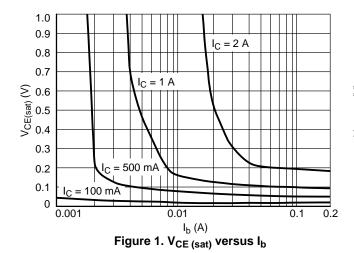
ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

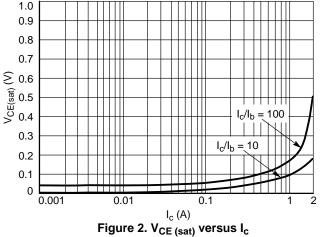
Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Collector – Emitter Breakdown Voltage ($I_C = 10 \text{ m}$	A, I _B = 0)	V _{(BR)CEO}	30	-	-	V
Collector-Base Breakdown Voltage ($I_C = 0.1 \text{ mA}, I_E = 0$)		V _{(BR)CBO}	50	-	-	V
Emitter-Base Breakdown Voltage ($I_E = 0.1 \text{ mA}, I_e$	_C = 0)	V _{(BR)EBO}	5.0	-	-	V
Collector Cutoff Current (V _{CB} = 30 V, I_E = 0)		I _{CBO}	-	-	0.1	μA
Collector–Emitter Cutoff Current ($V_{CES} = 30 \text{ V}$)		I _{CES}	-	-	0.1	μA
Emitter Cutoff Current (V _{EB} = 4.0 V)		I _{EBO}	_	-	0.1	μA
ON CHARACTERISTICS						
DC Current Gain (Note 4)		h _{FE}	300 300 200	500 -	_ 900 _	
Collector – Emitter Saturation Voltage (Note 4)		V _{CE(sat)}	- - -	0.10 0.06 0.05	0.200 0.125 0.075	V
Base-Emitter Saturation Voltage (Note 4) ($I_C = 1$.0 A, I _B = 0.1 A)	V _{BE(sat)}	-	-	1.1	V
Base-Emitter Turn-on Voltage (Note 4) ($I_C = 1.0$	A, V _{CE} = 2.0 V)	V _{BE(on)}	-	-	1.1	V

Output Capacitance (f = 1.0 MHz)

Cutoff Frequency (I_C = 100 mA, V_{CE} = 5.0 V, f = 100 MHz

4. Pulsed Condition: Pulse Width \leq 300 $\mu sec,$ Duty Cycle \leq 2%.





200

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300

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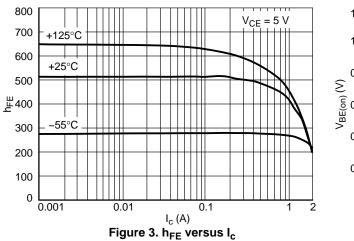
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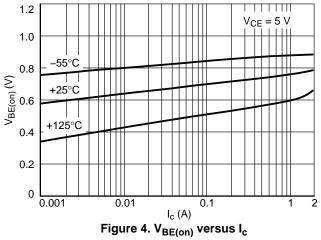
f_T

C_{obo}

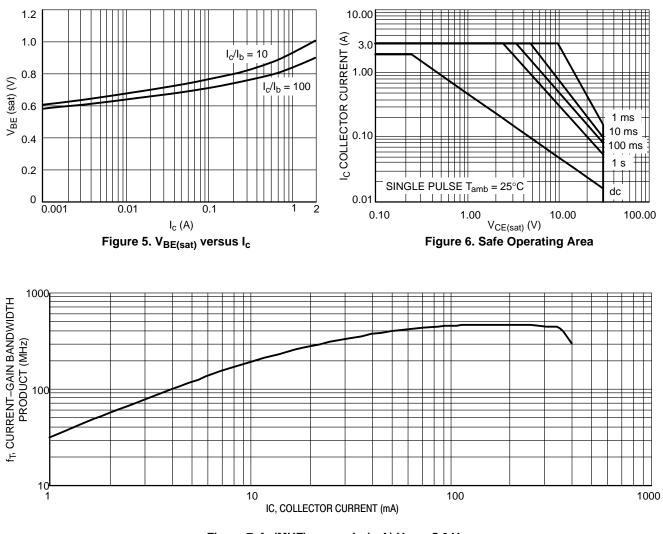
MHz

pF





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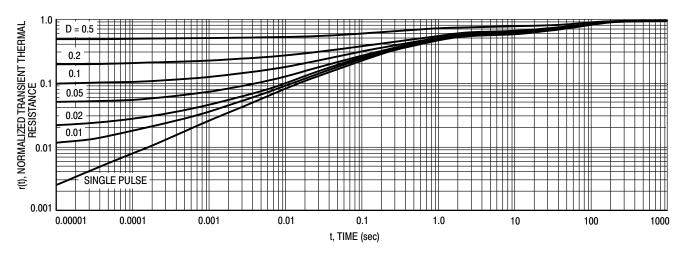


Figure 8. Normalized Thermal Response





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